

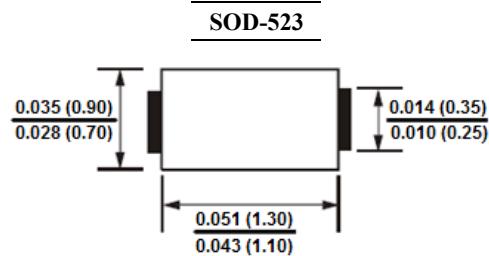
1N4148WT

FAST SWITCHING DIODES



FEATURES

- Fast Switching Device ($T_{RR} < 4.0 \text{ nS}$)
- General Purpose Diodes
- Surface Device Type Mounting
- Suffix "H" indicates Halogen-free parts, ex. 1N4148WTH

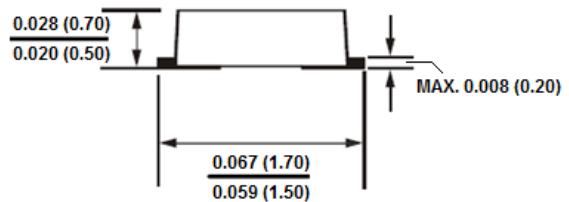


MECHANICAL DATA

Case : SOD-523

Polarity^b : Color band denotes cathode end

Mounting position : Any



Absolute Maximum Ratings

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	75	V
Non-Repetitive Peak Reverse Voltage	V_{RSM}	100	V
Continuous Forward Current	I_O	150	mA
Repetitive Peak Forward Current	I_{FRM}	300	mA
Power Dissipation	P_D	200	mW
Junction Temperature	T_J	150	°C
Storage Temperature Range	T_{stg}	-55 to +150	°C

Electrical Characteristics

$T_{amb} = 25^\circ\text{C}$, unless otherwise specified

Parameter	Symbol	Test Condition	Min.	Max.	Units
Forward Voltage	V_F	$I_F=10\text{mA}$	-	1.00	V
Reverse Leakage Current ^t	I_R	$V_R=20\text{V}$	-	25	nA
		$V_R=75\text{V}$	-	5	uA
Breakdown Voltage	B_V	$I_R=100\mu\text{A}$ $I_R=5\mu\text{A}$	100 75	-	V
Capacitance	C	$V_R=0\text{V}, f=1\text{MHz}$	-	4	pF
Reverse Recovery Time	T_{RR}	$I_F=10\text{mA}, I_R=60\text{mA}$ $R_L=100\Omega, I_{RR}=1\text{mA}$	-	4	nS

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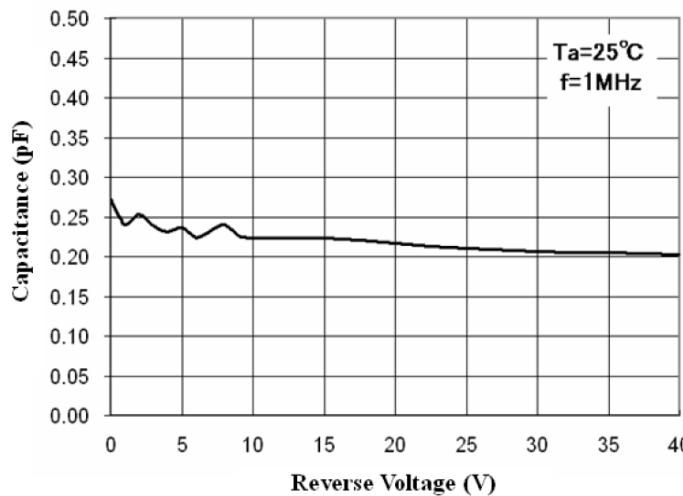
FAST SWITCHING DIODES



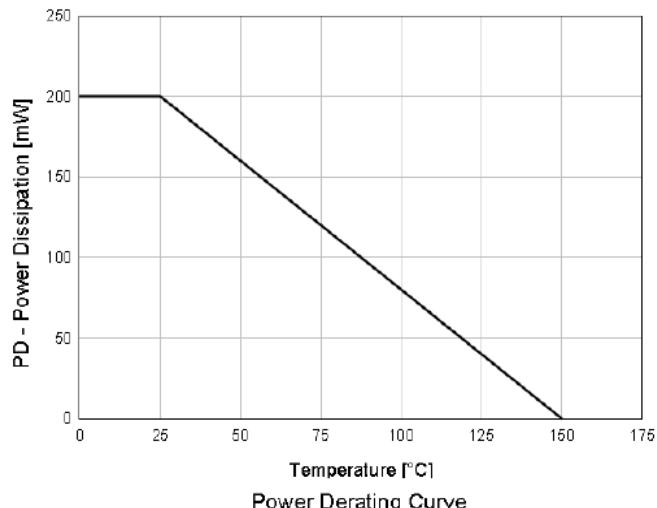
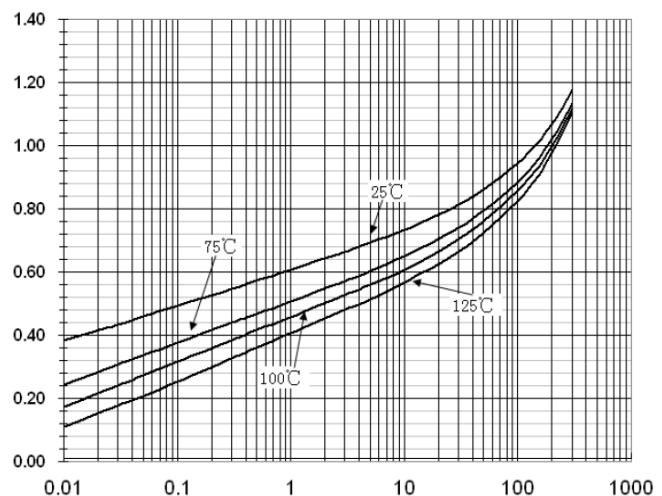
康比電子
HORNBY ELECTRONIC

RATINGS AND CHARACTERISTIC CURVES

Total Capacitance



Forward Voltage vs Ambient Temperature



Power Derating Curve

Reverse Current vs Reverse Voltage

